NSN 5961-01-112-8431

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-112-8431 **Inclosure Material:** Metal **Overall Length:** 5.500 inches **Electrode Internally-electrically Connected To Case:** Anode **Mounting Method:** Threaded stud and unthreaded hole **Terminal Circle Diameter:** Between 0.266 inches and 0.296 inches **Features Provided:** Hermetically sealed case **Thread Size:** 0.375 inches **Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 600.0 repetitive peak reverse voltage and 600.0 working peak reverse voltage and 720.0 nonrepetitive peak reverse voltage and 420.0 reverse voltage, total rms **Current Rating Per Characteristic:** 100.00 amperes forward current, average absolute **Maximum Operating Tempurature Per Measurement Point:** 190.0 degrees celsius junction **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 tab w/wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: